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Khan et al.

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(54) **PACKAGE 3D INTERCONNECTION AND METHOD OF MAKING SAME**

H01L 2224/16225 (2013.01); *H01L 2224/16227* (2013.01); *H01L 2224/32225* (2013.01);
(Continued)

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USPC 438/126
See application file for complete search history.

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Related U.S. Application Data

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H01L 21/56 (2006.01)

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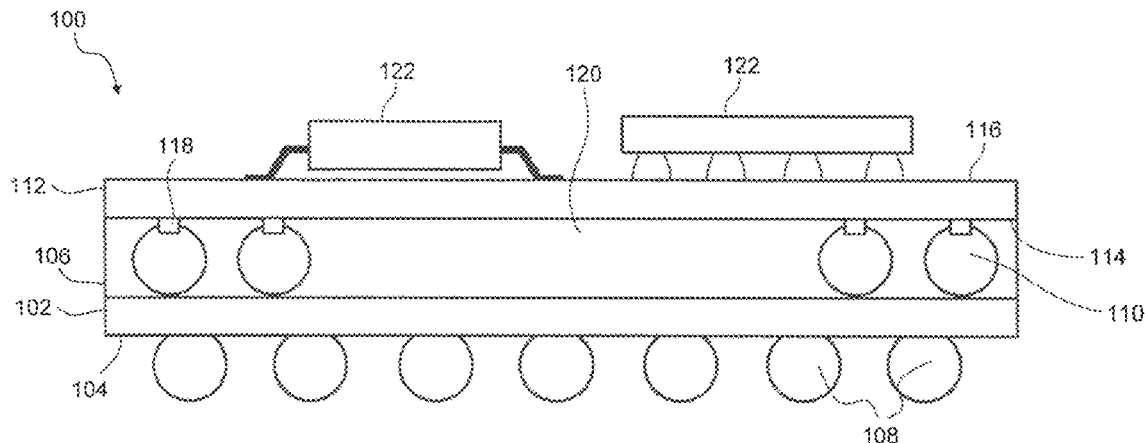
(57) **ABSTRACT**

A method of manufacturing an integrated circuit (IC) package is provided. The method includes mounting a first plurality of contact members on a surface of a package member, and coupling a second plurality of contact members located on a first surface of an interposer substrate to corresponding ones of the first plurality of contact members. The interposer substrate is configured such that a circuit member mounted to a second surface of the interposer substrate is electrically coupled to the first plurality of contact members.

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20 Claims, 16 Drawing Sheets



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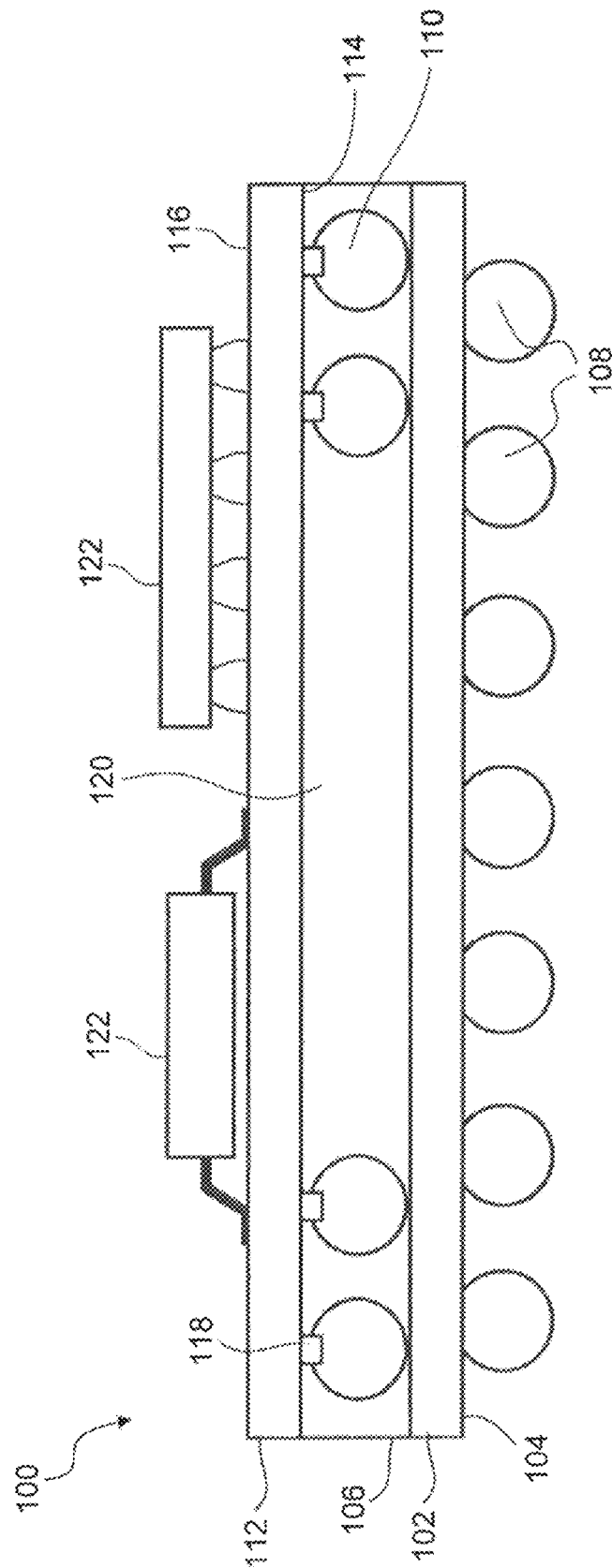


FIG. 1

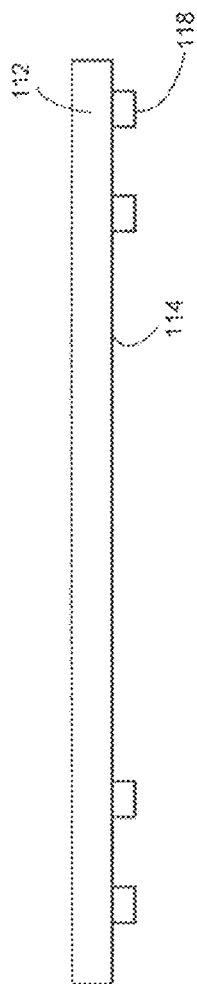


FIG. 2A

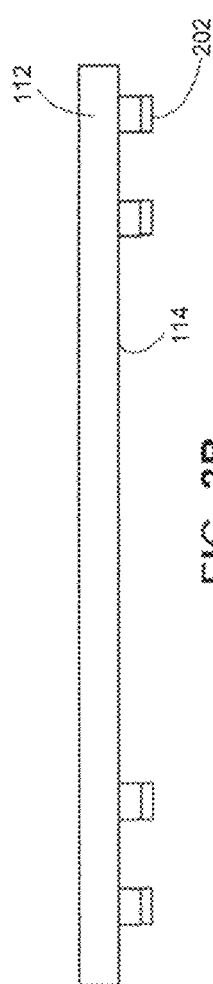


FIG. 2B

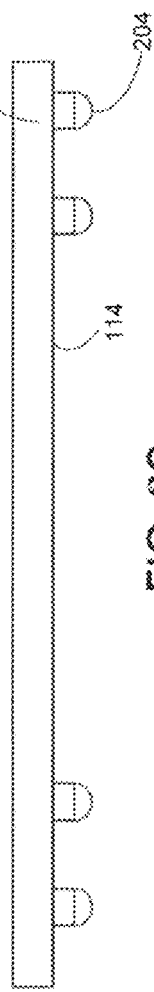


FIG. 2C

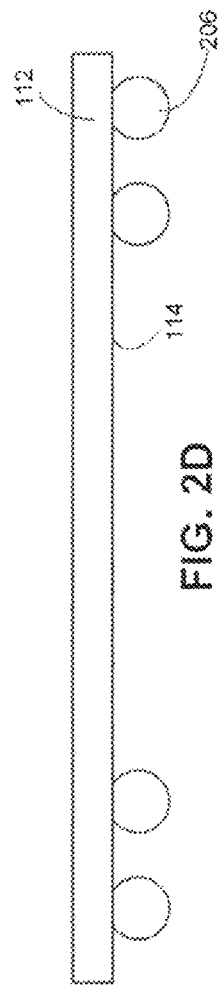


FIG. 2D

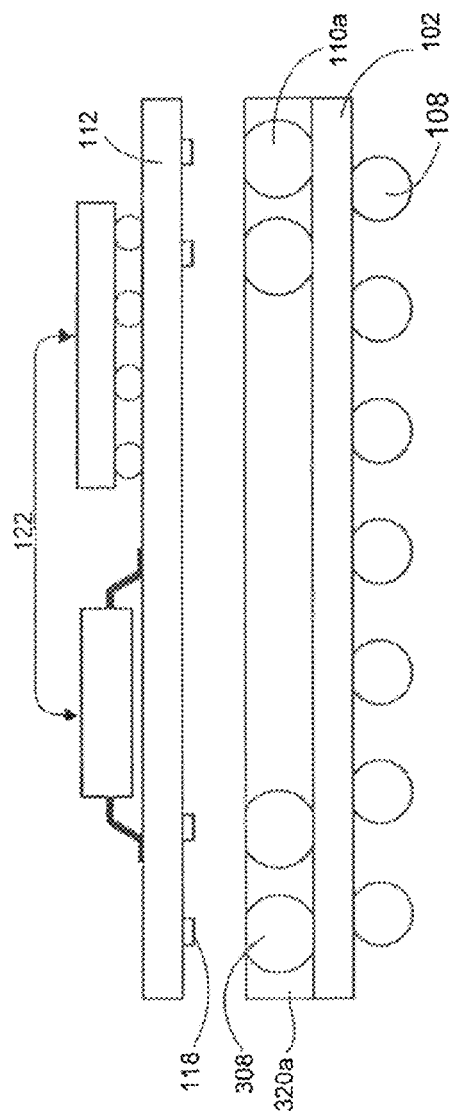


FIG. 3A

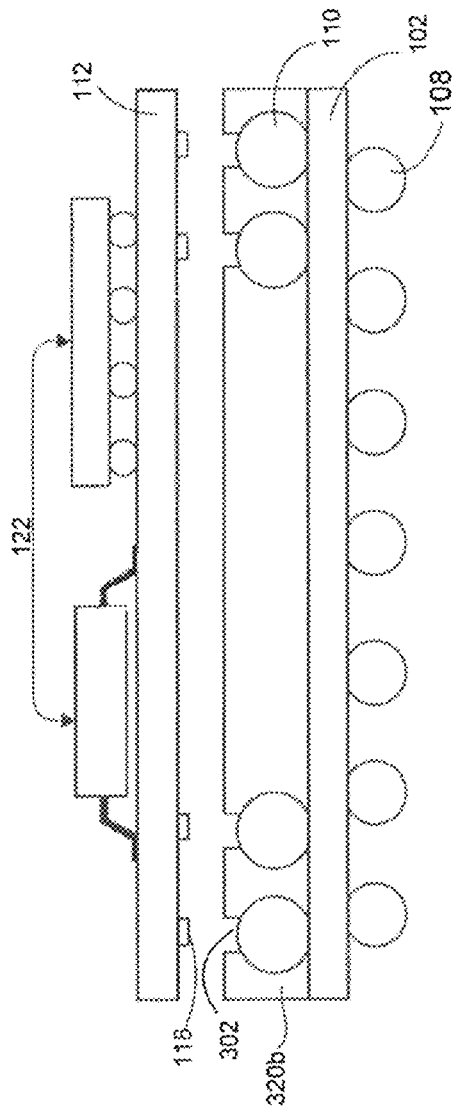
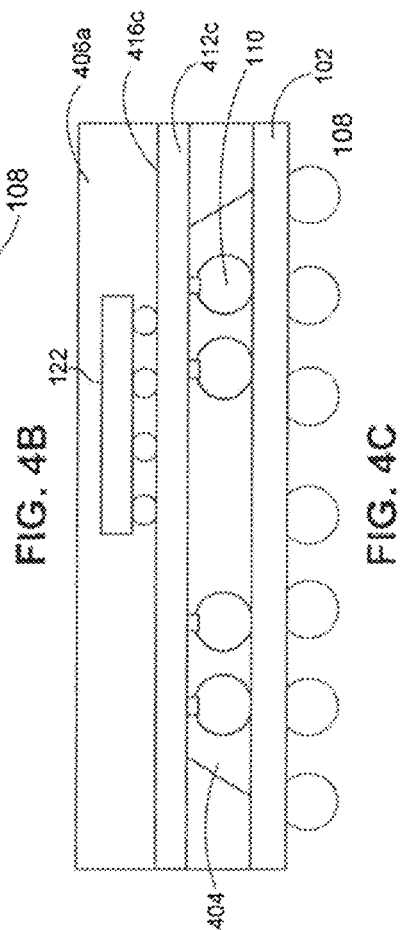
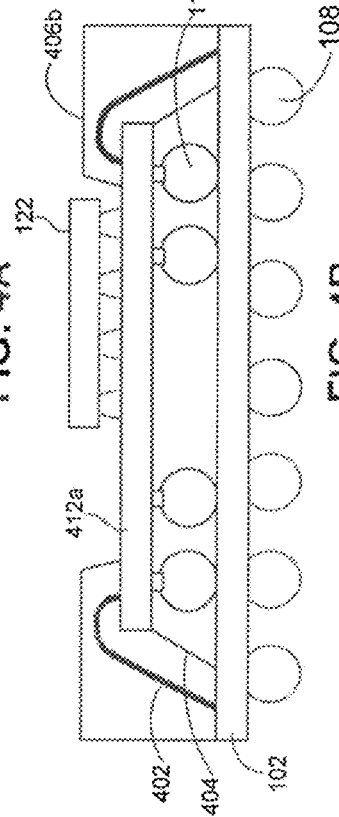
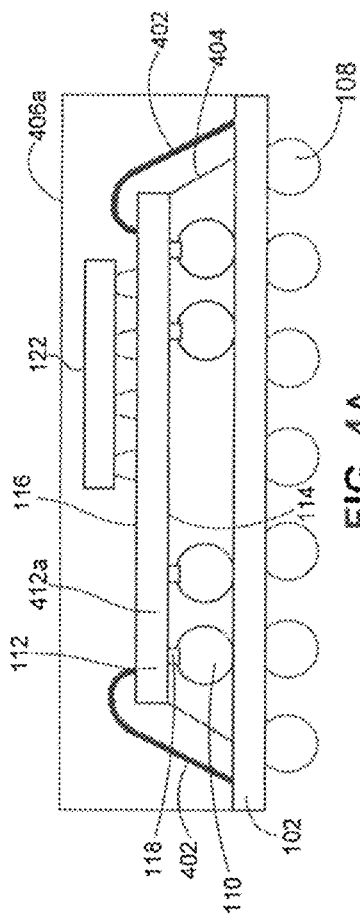


FIG. 3B



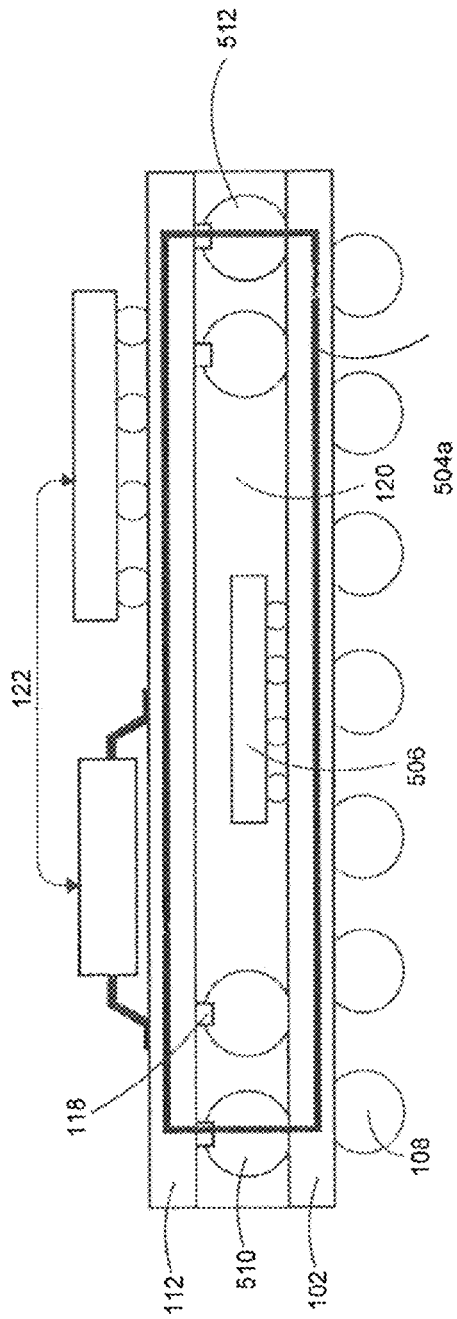


FIG. 5A

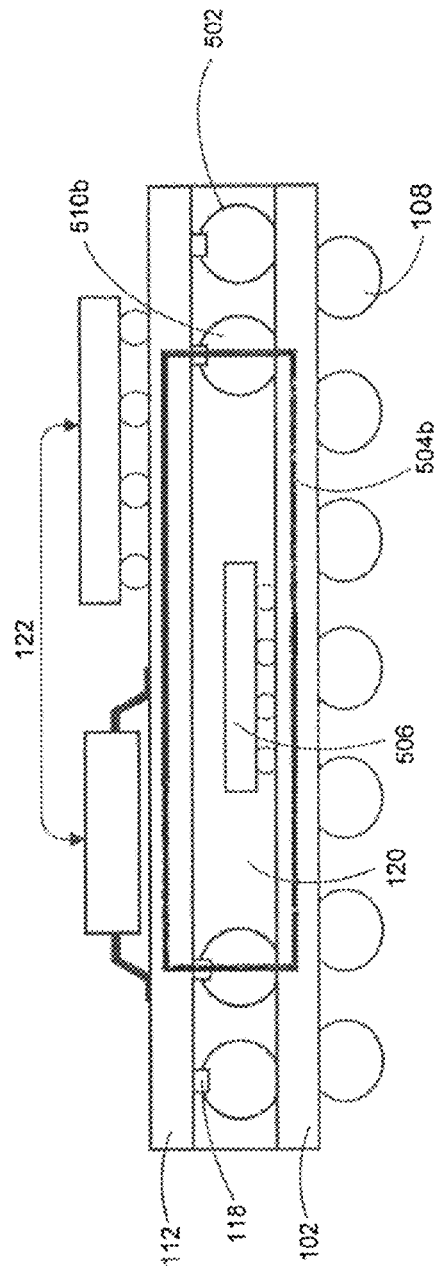
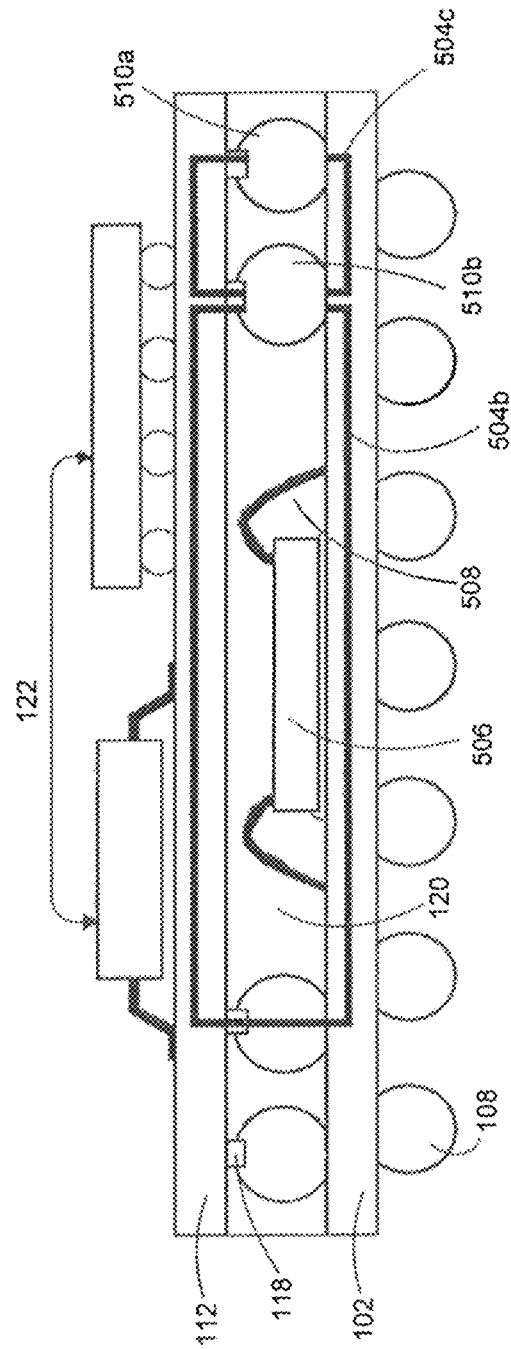


FIG. 5B



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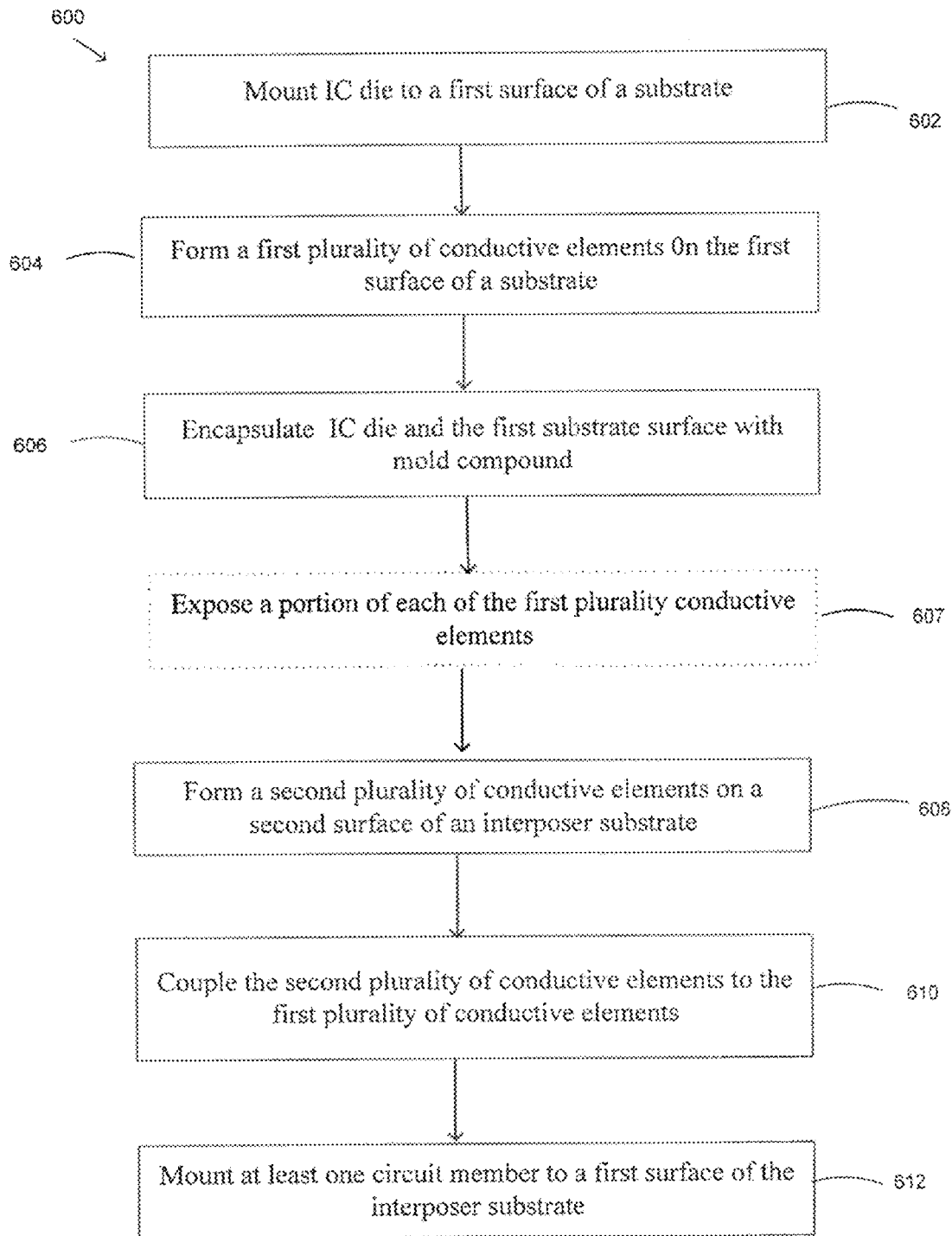
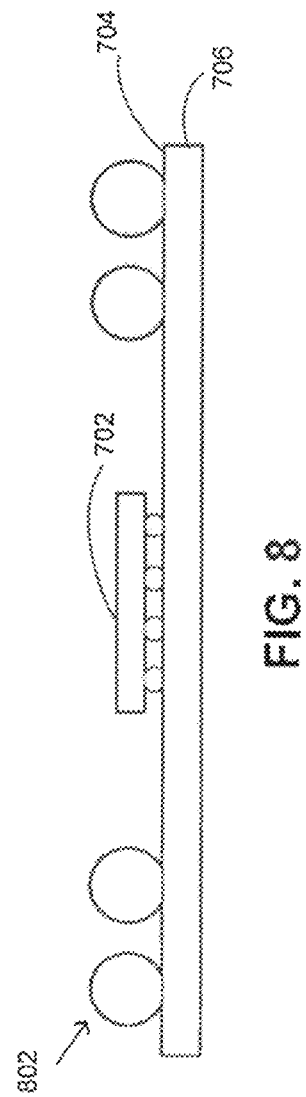
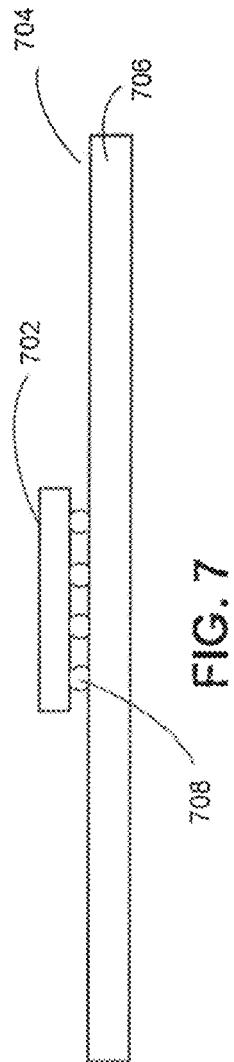
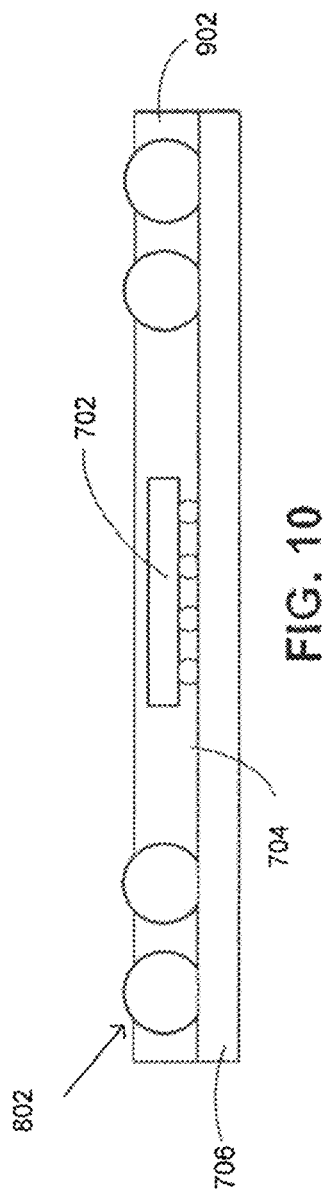
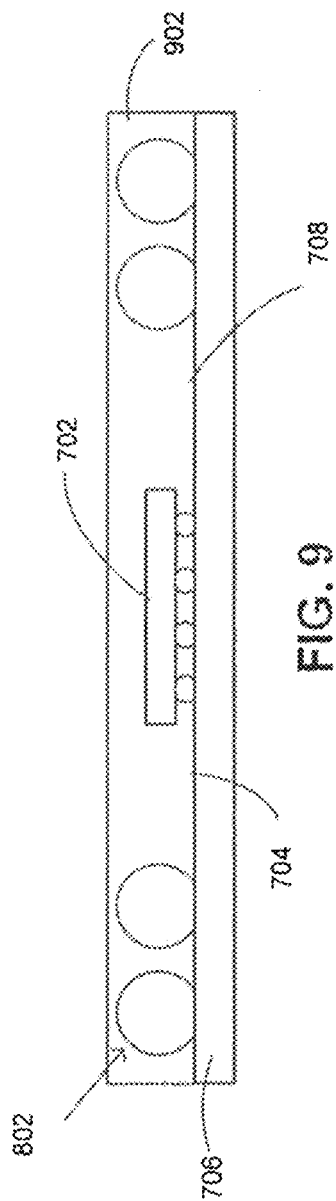
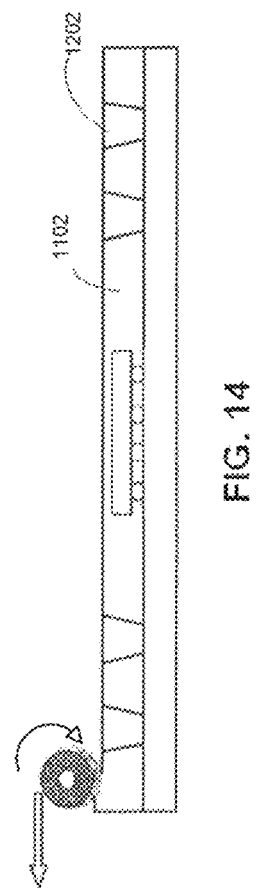
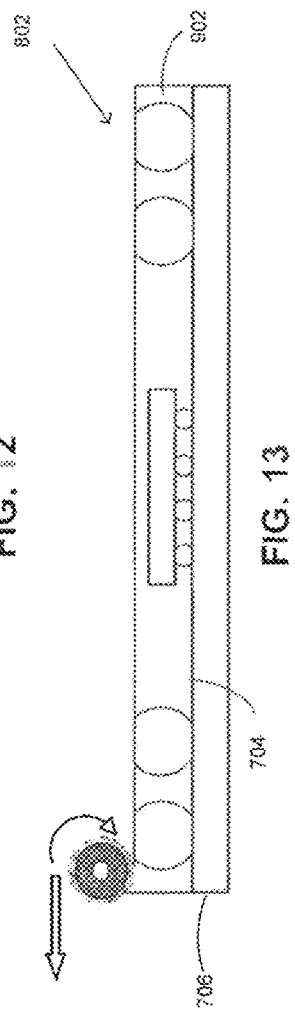
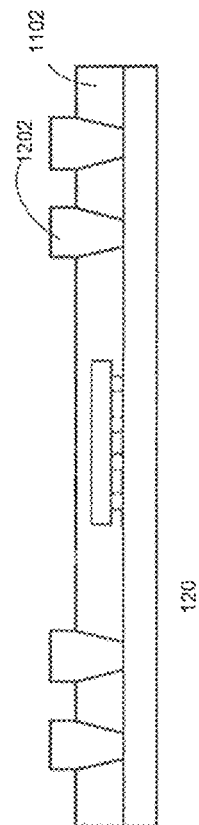
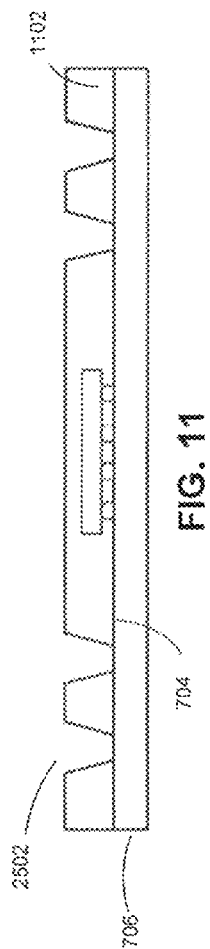


FIG. 6







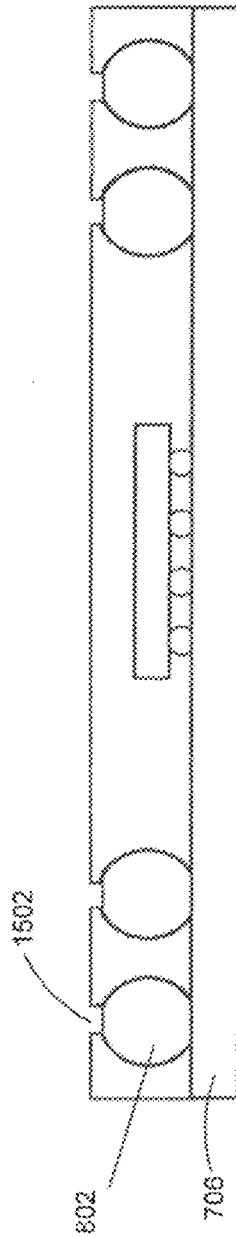


FIG. 15

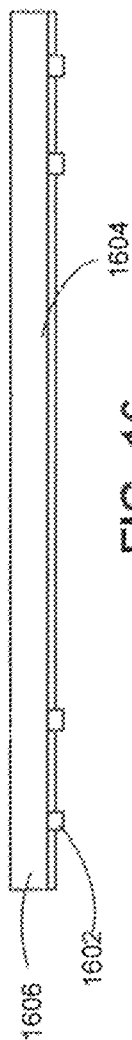


FIG. 16

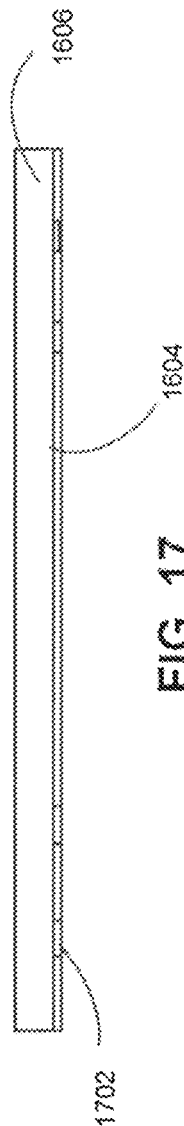


FIG. 17

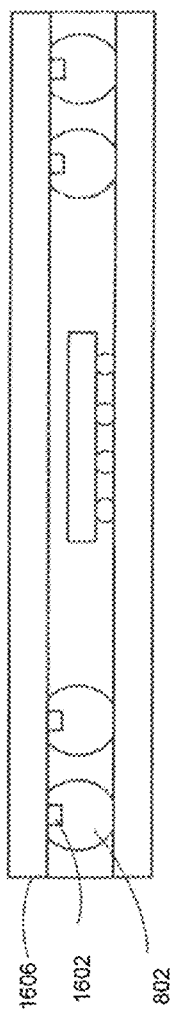


FIG. 18

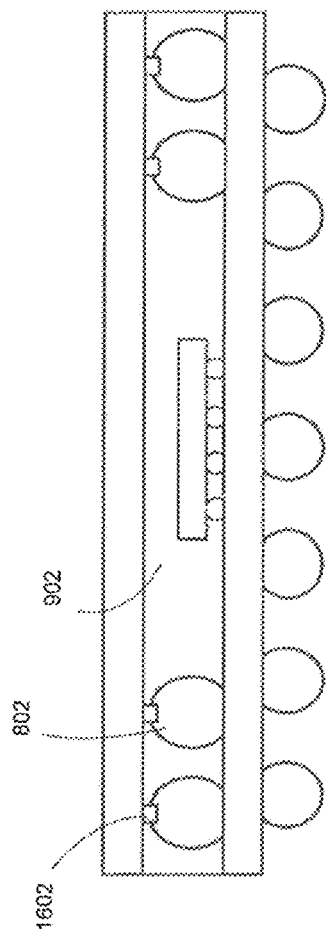


FIG. 19

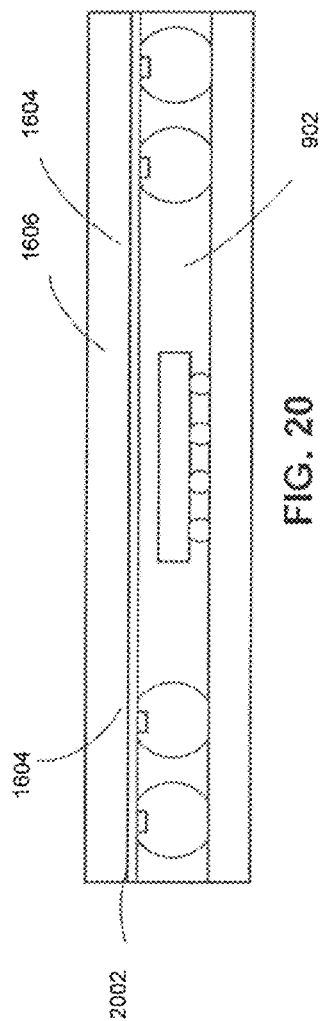


FIG. 20

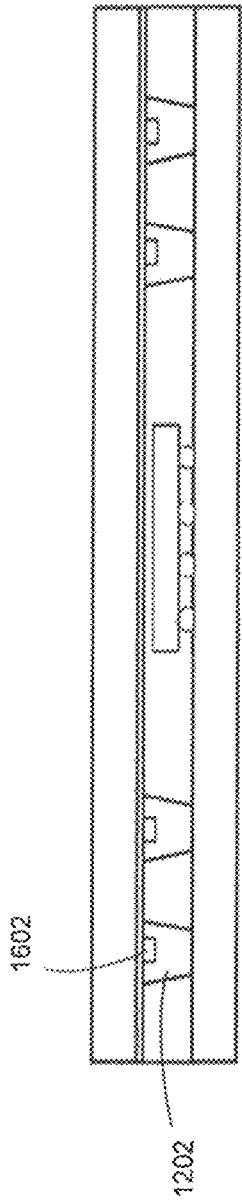


FIG. 21

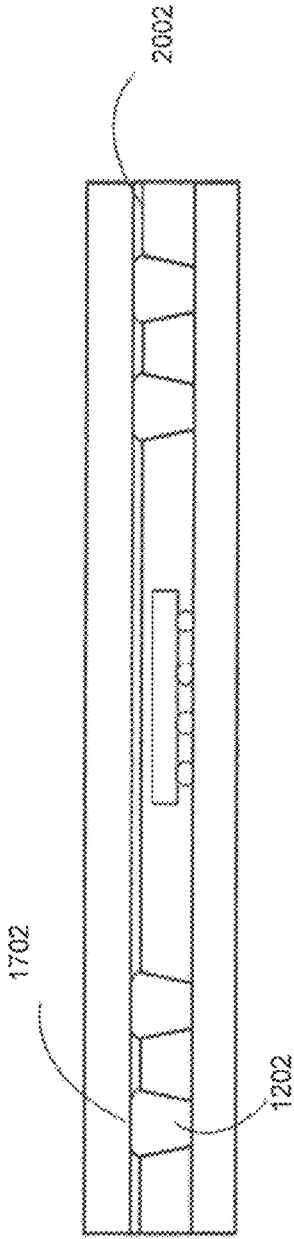


FIG. 22

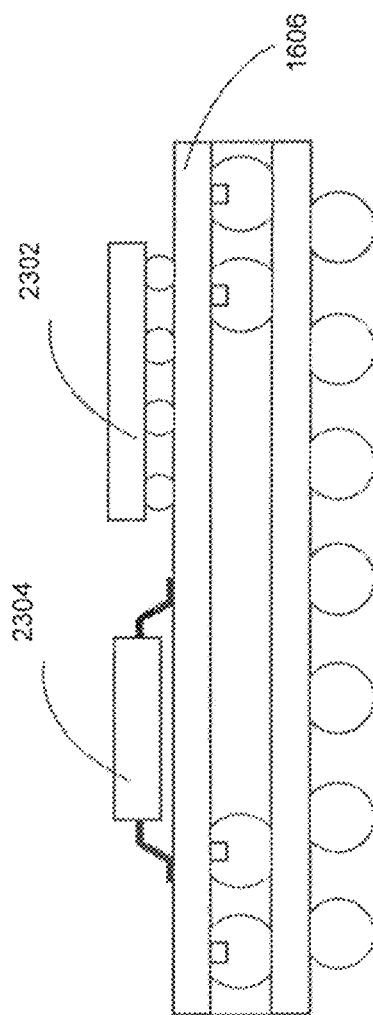


FIG. 23

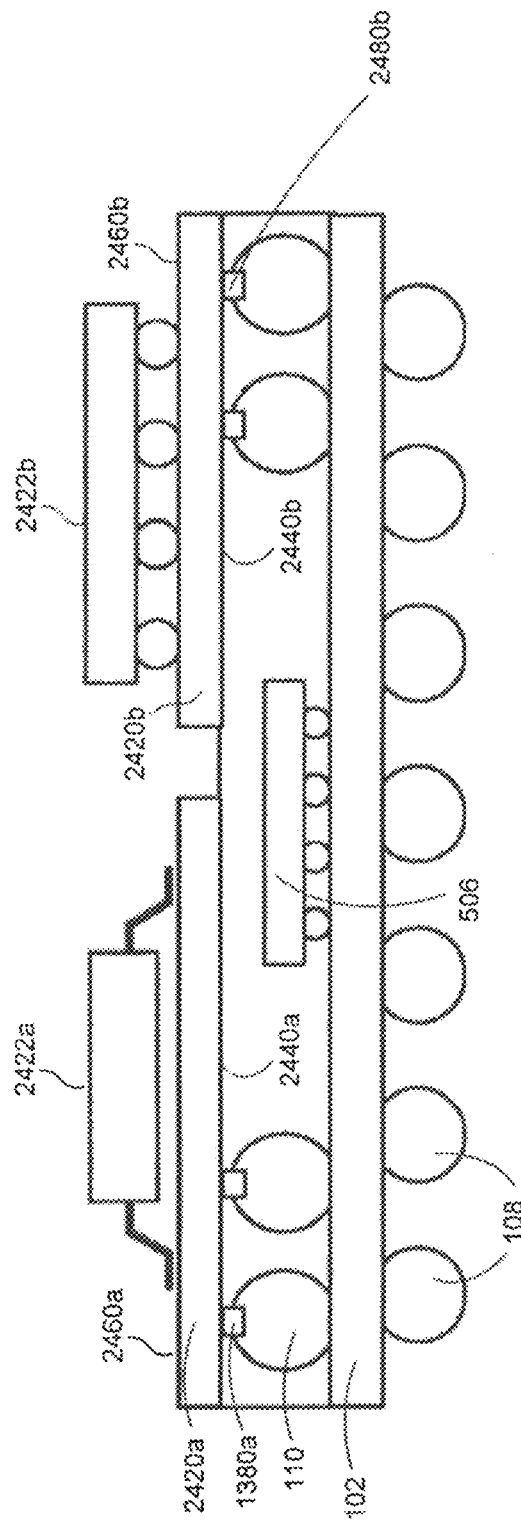


FIG. 24

PACKAGE 3D INTERCONNECTION AND METHOD OF MAKING SAME

CROSS REFERENCE TO RELATED APPLICATIONS

This application is a divisional of U.S. patent application Ser. No. 13/174,066, filed Jun. 30, 2011 (now allowed), which claims the benefit of U.S. Provisional Appl. No. 61/448,880, filed Mar. 3, 2011, all of which are incorporated by reference herein in their entireties.

BACKGROUND

1. Field

Embodiments described herein generally related to integrated circuit (IC) device packaging technology.

2. Background

Die-up plastic ball grid array packages were first introduced by Motorola and were called Overmolded Plastic Pad Array Carriers (OMPAC) (See, B. Freyman, and R. Pennisi, "Overmolded Plastic Pad Array Carriers (OMPAC): A Low Cost, High Interconnect Density IC Packaging Solution for Consumer and Industrial Electronics", Electronic Components and Technology Conference, IEEE, pp. 176-182, 1991). Commonly known as a PBGA package, the plastic ball grid array package features a plastic printed circuit board (substrate) typically made of BT (Bismaleimide Triazine) resins or FR4 materials.

Conventional PBGA packages have the drawbacks of (1) poor thermal performance, (2) no EMI protections, (3) thick top mold and overall package profile height, (4) small ratio of die-to-package size since the mold cap must be clamped to the package substrate for molding, and (5) large package body size. Both the resin substrate and the plastic molding compound materials have low thermal conductivity values molding compound). Since the die is surrounded entirely by materials with poor heat conduction properties, the heat generated on the IC die is trapped within the PBGA package. The temperature of the IC die has to rise to very high values above the environment temperature in order to release the trapped heat to the environment.

Both the resin substrate and the plastic molding compound materials are transparent to electromagnetic radiation. Consequently, electromagnetic radiation generated from the IC device will escape from the package and enter the electronic system and interfere with other electronic components. The IC device is also unprotected from electromagnetic radiation emitted from other components inside as well as outside the electronic system.

The mold thickness of the joint Electron Device Engineering Council (JEDEC) standard PBGA packages is 1.17 mm. At a mold thickness of 1.17 mm, the overall heights of PBGA packages commonly are in the range of 1.5 mm~2.5 mm. For mobile applications such as hand-held communication devices (cell phones, global positioning devices, watch-size communication devices, etc.), mobile multimedia (video/audio) players, wireless personal area networking devices such as Bluetooth headset, and flash memory devices such as memory cards, paper-thin packages are desirable to enable small electronic devices for these applications.

A mold chase with multi-cavity mold caps is used for mold encapsulation of JEDEC standard PBGA packages. Each individual substrate unit in a substrate strip or panel has a corresponding mold cap for molding using thermoset molding epoxy. This is necessary in order to clamp the mold chase to the package substrate peripheral in a transfer molding

process. The periphery of the substrate top surface is exposed (not covered by the molding compound). Both the IC die and wirebond interconnections from the die edge to the package substrate must be placed within the mold cavity. Additionally, the IC die and the wirebond must be kept at a sufficient distance away from the inner walls of the mold cavity to allow mold flow and avoid wire sweeping. Consequently, the size of the IC die is confined by the size of the mold cap (mold cavity). For a given size of substrate, the allowed maximum size of the die is substantially smaller than the size of the substrate.

Conventional PBGA packages are typically large in body size, ranging from 19 mm×19 mm and above. A large package size is undesirable for mobile applications where bulky electronic components make for bulky devices. To reduce package size, chip scale packages have been developed where the size of the IC die is very close to the size of the package. In addition to the smaller solder balls and smaller ball pitch used for a fine pitch ball grid array (FBGA) package, the mold thickness is reduced to 0.25 mm~0.7 mm. The molding compound covers the entire top surface of FBGA package that enables the increase of die size to substrate size ratio.

Dreiza et al. reported stacked packages using wirebonded bottom PSvfBGA (package stackable very thin fine pitch BGA) (M. Dreiza, A. Yoshida, J. Micksch, and L. Smith, Implement Stacked Package-on-Package Designs, http://www.eetasia.com/ART_8800379158_480100_TA_db7b00bf.HTM). The package-to-package interconnection is facilitated by mounting the top ball grid array (BGA) package to the substrate of the bottom package. The bottom package has exposed land pads on the substrate top surface which provide contact with the solder balls on the top BGA package. The exposed solder ball land pads are located along the periphery of the substrate top and surround the package molding compound. The top package can be attached to the bottom package using conventional reflow surface mount processes. The PSvfBGA provides the added advantage of reducing overall package stack height by placing the IC die of the bottom package within a window opening in the substrate center.

Because the solder ball land pads on the bottom package substrate top must be exposed for stacking the top package, the IC die of the bottom package must be encapsulated with a mold cavity (mold cap) to define the extent of the mold and prevent the mold compound from covering or contaminating the ball pads. Consequently, the die size in the bottom package can not be too large in order for both the die and bond wires to fit into the mold.

Improvements in EMI shielding have been made for BGA type of IC packages. U.S. Pat. No. 7,432,586, issued Oct. 7, 2008, and commonly owned with the present disclosure, proposes a metal shield integrated into a die-up wire bond ball grid array (BGA) package for both EMI isolation and thermal improvement. The disclosure of the '586 patent is incorporated herein by reference in its entirety as though set forth in full below. In the design disclosed in the '586 patent, an IC die is enclosed inside a top metal structure and a bottom metal structure. The top metal structure is shaped like an inverted cup. The top metal structure is in contact with a flat metal structure at the bottom portion of the mold body. An IC die is mounted on the flat bottom metal structure. Ambient EMI radiations are blocked by the grounded top and metal structures from interfering with the operation of the IC die. This design provides an enclosed metal box, a Faraday cage, for EMI shielding within a wire bond BGA package. For a flip

3

chip die, however, the metal box structure disclosed in the '586 patent cannot provide an interconnection between the IC die and the substrate.

Ideally in package-on-package devices, both the bottom and top packages in the package stack are the same size and type of packages with exactly the same structure (same size of die, same substrate or die carrier design and structure, etc.) in order to minimize stress match between packages. However, interconnections between stacked wirebond packages are most easily made between the package substrates. To provide a vertical package interconnection, the bottom package substrate is partially exposed along the substrate periphery. A transfer mold process with a mold cap cavity smaller than the substrate size must be used. This requirement to partially expose the substrate top surface for package-to-package interconnection purposes limits the bottom package to a PBGA package, or package with similar features. In order to minimize stress mismatch, the top package is also limited to a transfer molded BGA package such as a PBGA package. For an overmold package such as a fine pitch ball grid array (FBGA), it can only be used for the top package because the FBGA substrate top is entirely covered by the mold compound.

Moreover, stacking of FBGA packages can be desirable to reduce the overall footprint size of stacked packages and to reduce overall stacking height (or increase the number of packages in a package stack for as given height) by taking advantage of chip scale design feature and thin mold chase of the FBGA package.

BRIEF DESCRIPTION OF THE DRAWINGS/FIGURES

The accompanying, drawings, which are incorporated herein and form a part of the specification, illustrate the present disclosure and, together with the description, further serve to explain the principles of the disclosure and to enable a person skilled in the pertinent art to make and use the disclosure.

FIG. 1 illustrates a view of a vertical/3-dimensional package interconnection with an interposer substrate.

FIGS. 2A-2D illustrates views of various embodiments of an interposer substrate.

FIG. 3A illustrates a view of a further embodiment of a vertical/3-dimensional package interconnection with an interposer substrate having a truncated mold top.

FIG. 3B illustrates a view of a further embodiment of a vertical/3-dimensional package interconnection with an interposer substrate having drilled mold top contact pads.

FIG. 4A illustrates a view of an embodiment of a System in Package (SiP) having a molded interposer substrate.

FIG. 4B illustrates a view of an embodiment of a SiP having a partially exposed interposer substrate.

FIG. 4C illustrates a view of an embodiment of a SiP having an interposer substrate which is substantially the same size as the bottom package.

FIG. 5A illustrates a view of an embodiment having EMI shield and system partitioning with a ground/power bus along an outer row of a molded BGA for EMI shield and system partitioning.

FIG. 5B illustrates a view of an embodiment having EMI shield and system partitioning with a ground/power bus along an inner row of a molded BGA for EMI shield and system partitioning.

FIG. 5C illustrates a view of an embodiment having EMI shield and system partitioning with signal partitioning.

4

FIG. 6 illustrates an example flowchart for manufacturing IC packages, according to exemplary embodiments of the present disclosure.

FIG. 7 illustrates a view of an IC die attached to a surface of a substrate.

FIG. 8 illustrates a view of an IC die and conductive elements formed on a surface of a substrate.

FIG. 9 illustrates a view of a plurality of solder balls, an IC die, and a first surface of a substrate encapsulated in mold compound.

FIG. 10 illustrates a view of solder balls exposed above a mold top surface.

FIGS. 11-12 illustrate steps in forming through mold vias (TMV) using solder paste.

FIGS. 13 and 14 illustrate views of devices after removal of layers of a mold compound.

FIG. 15 illustrates a view of mold compound having holes that expose respective solder balls.

FIGS. 16 and 17 illustrate views of interposer substrates having conductive posts and contact pads, respectively.

FIGS. 18-22 illustrate views of interposer substrates coupled to a substrate.

FIG. 23 illustrates a view of a component attached on a surface of an interposer substrate.

FIG. 24 illustrates a view of a package interconnection embodiment with multiple interposer substrates.

The present disclosure will now be described with reference to the accompanying drawings. In the drawings, like reference numbers indicate identical or functionally similar elements. Additionally, the left-most digit(s) of a reference number identifies the drawing in which the reference number first appears.

DETAILED DESCRIPTION

Introduction

It is noted that references in the specification to "one embodiment", "an embodiment", "an example embodiment", etc., indicate that the embodiment described may include a particular feature, structure, or characteristic, but every embodiment may not necessarily include the particular feature, structure, or characteristic. Moreover, such phrases are not necessarily referring to the same embodiment. Further, when a particular feature, structure, or characteristic is described in connection with an embodiment, it is submitted that it is within the knowledge of one skilled in the art to effect such feature, structure, or characteristic in connection with other embodiments whether or not explicitly described.

Furthermore, it should be understood that spatial descriptions (e.g., "above", "below", "left", "right", "up", "down", "top", "bottom", etc.) used herein are for purposes of illustration only, and that practical implementations of the structures described herein can be spatially arranged in any orientation or manner.

The embodiments described herein provide a methodology for package vertical interconnection interconnections through an embedded vertical interconnection structure within an IC package. The package vertical interconnection structure is a molded ball grid array or molded conductor posts as disclosed in U.S. patent application Ser. No. 11/589,120, filed Oct. 30, 2006 by Zhao and Khan, and commonly assigned with the present disclosure; the disclosure of the '120 application is incorporated herein by reference in its entirety, as though set forth in full below. The molded vertical interconnect elements are partially exposed through the top surface of the package mold compound, forming contact pads

on the package top. The contact pads for interconnection provide landing pads for electrical interconnection on top of the mold compound. A printed circuit board, called an interposer substrate herein, is connected to the contact pads on the package mold top. The interposer substrate has one or more conductor posts or solder bumps or balls on its bottom as interconnect terminals. The through the mold compound interconnection structure of the bottom package provides direct interconnection between the package bottom substrate and the interposer substrate on the package mold top. The interposer substrate provides an interface structure for package-to-package vertical interconnection. The interposer substrate top has contact pads for interconnection with other surface mountable components such as ASICs and memory device packages including flip chip and wire bond BGAs, passive components such as capacitors, inductors, electromagnetic coupling balms, electromagnetic radiators, resistors, etc.

The disclosure is related to (1) a system in package (SiP) technology, (2) a package-on-package (PoP) vertical interconnection technology of two or more ball grid array (BGA) packages, (3) a low profile package PoP design, (4) enabling stacking of chip-scale packages, (5) reduction of electromagnetic interference (EMI) and providing EMI shielding, (6) thermal performance enhancement technologies for IC packages, (7) electrical performance enhancement technologies for IC packages, and (6) high speed communication applications.

One or more integrated circuit (IC) dies may be attached directly to the top surface of the printed circuit substrate using epoxy. Wire bonds can be used to electrically connect an IC die to the printed circuit on the substrate. A matrix of solder balls is mounted on the bottom side of the substrate.

The IC die and the wire bonds are protected from the environment by a plastic molding compound which encapsulates both the IC die and the wire bonds and covers the center region on the top surface of the substrate. The periphery of the substrate top surface can be exposed.

Conventional IC die encapsulation processes such as dam-and-fill (glob top), mold cap injection molding (transfer molding), strip or panel over-molding (mold compound covers the edges of package substrate) can be used in the proposed designs for both top and bottom packages. The interconnection structure can be used for wire bond ball grid array (BGA) packages, such as fine pitch BGA (FBGA) and plastic BGA (PBGA), and flip chip packages. The disclosed structure can also be used for package stacking of land grid may (LGA) packages, leadframe and flip chip packages stacking on BGA package, and their combinations.

Stacking of packages on top of one another requires electrical interconnections between the external terminals of the top and bottom packages. Overmolded area array packages such as FBGA and LGA packages do not have electrical signal interconnect terminals on the package top surface. The same problem exists for certain type of leadframe packages such as no-lead quad flat package (QFN, also known as MLP, MLF, and LPCC packages) as well as thin array plastic package (TAPP) (see, e.g., U.S. Pat. No. 7,482,690, issued Jan. 27, 2009, titled "Electronic Components Such As Thin Array Plastic Packages And Process For Fabricating Same." Consequently, these packages cannot have other packages stacked on their top.

A solution using truncated solder balls molded within the package molding compound and extended to the top of the mold on the package top provides electrical contact pads on the mold top with other packages. Because the solder balls can be embedded within the mold of the bottom package, the

package-to-package interconnect contact pads do not have to be placed outside the mold of the bottom package as required in the stacked packages. Therefore, the footprint of the stacked packages can be minimized. In mobile applications such as cell phones, hand-held video and audio players, smaller footprint size of system in package (SiP) usually translates into smaller application devices. Conductor posts through the package mold can also be used for the bottom package contact pads with top mounted component.

However, contact pads provided directly on the bottom package mold top have the drawback of a large variation of pad diameter, pad placement location accuracy, and pad-to-pad pitch. These problems made it difficult to mount components requiring a high precision of interconnect contact pads on the bottom package. For example, fine pitch components with electrical contact pitch smaller than 0.40 mm may be difficult to mount on top of the bottom package mold due to high yield loss caused by short or open at the electrical contact terminals. A solution to this problem is to use an interposer substrate between the bottom package and top mounted components. The interposer substrate can have interconnect terminals or pads on its bottom with size and terminal-to-terminal pitches suitable for the interconnection with the contact pads on the bottom package mold top. The interposer substrate also has electrical interconnect contact pads on its top for receiving surface mountable components such as IC packages and passive components. Interconnect terminal pitches are typical larger on the interposer substrate bottom than the pitches of contact pads on the interposer substrate top to accommodate lower manufacturing control tolerance for contact pads on the bottom package. From an interconnect pitch standpoint the interposer substrate acts as a transition from a larger interconnect pitch on the bottom to a smaller interconnect pitch on the top. It is also possible to have a smaller interconnect terminal pitch on the interposer substrate bottom and a larger interconnect terminal pitch on top. The same interconnect terminal pitches on both sides of the interconnect substrate are also possible with the interposer substrate. In essence, the interposer substrate is an interconnect structure that facilitates vertical interconnection between packaged components.

Because the solder balls are placed directly on the contact pads of the bottom die, the electrical interconnection path length from the IC die in the bottom package to the IC die in the top package is substantially reduced. Consequently, the impedance of the interconnection can be reduced substantially and higher speeds for signal transmission between the IC dies can be realized.

Disclosed herein are structures and implementations of package-to-package direct interconnection structure embedded within a plastic mold compound and exposed on the plastic mold top surface. Applications of the interconnection contact pads on molded IC chips for package stacking and various structures of stacked packages are also disclosed herein.

FIG. 1 illustrates a view of the structure of a vertically integrated IC package **100**. IC package **100** has a first or bottom package substrate **102**. First substrate **102** had a first or bottom surface **104** and a second or top surface **106**. Solder balls **108** are fixed to first surface **104** in physical and electrical contact with second surface **106**. Solder balls **108** are attached to pads (not shown) on first surface **106** of first package substrate **102**. Solder balls **110** are attached to pads (not shown) on second surface **106** of substrate **102**.

IC package **100** further includes a second or interposer substrate **112** which is spaced from first substrate **102**. Interposer substrate **112** has a first or bottom surface **114** and a

second or top surface **116**. One or more, typically a plurality, of conductor posts or pillars **118** are physically and electrically connected to first surface **114** of interposer substrate **112**. Conductor posts **118** physically and electrically mate with corresponding contact pads (not shown) on first substrate **102** via solder balls **110**. In another embodiment, one or more of conductor posts **118** can be replaced with small solder balls or other types of interconnection elements, as would be appreciated by those skilled in the art based on the description herein. Conductor posts **118** can be formed out of copper, aluminum, or other materials used to form conductive interconnection elements, as would be appreciated by those skilled in the relevant art based on the description herein. A mold compound **120** is interposed between first and second substrates **102** and **112**.

Solder balls **110** may be molded within molding compound **120**, as disclosed in U.S. Pat. No. 7,714,453, issued May 11, 2010, titled "Interconnect Structure And Formation For Package Stacking Of Molded Plastic Area Array Package," and commonly assigned with the present disclosure. The disclosure of the '453 patent is incorporated herein by reference in its entirety as though set forth in full below.

As described in more detail below, after molding and post mold curing, solder balls **110** may be entirely encapsulated in the molding compound **120**. The top of the solder balls could also be partially exposed if the solder ball height is at or very close to the thickness of the mold cap. A top layer of molding compound **120** is subsequently removed and, in the process, the top of solder balls **110** are truncated simultaneously to expose the circular pads formed by the truncated solder spheres that are embedded in mold compound **120**. Other methods, such as mechanical drilling, chemical etching, etc., as disclosed in the '120 patent, can also be used to expose solder balls **110**. In addition, laser ablation can also be used to remove mold compound **120** and expose solder balls **110** to make interconnect contact pads on bottom package top surface **106**. These exposed circular pads provide contact terminals on the mold top.

The second or top surface **116** of interposer substrate has one or more, typically a plurality, of contact pads (not shown) on its surface. These contact pads can be used to connect electronic components **122** for package-to-package electrical interconnections such as package stacking to form a package-on-package (PoP) stack. Multiple electronic components, including packaged IC devices, inductors, capacitors, and resistors can all be attached to the package mold top on these exposed pads.

There are various methods to make contact pads on the bottom package mold top surface **106** through exposing the top of the molded solder balls **110**. Examples of implementation by removing a layer of package mold top and to truncate and expose the embedded solder balls are illustrated in the '120 application. An advantage of removing an entire layer of package mold compound **120** is that the contact pads formed are on the same surface as the top surface of mold compound **120**. Conductor posts **118** can be used as the terminals to contact bottom package substrate **102** through interconnect solder balls **110**. Manufacturing tolerances for both the bottom package warpage and interposer substrate **112** can also be increased and still allow the interconnection contact when the contact pads are on the top plane of the bottom package. When the bottom package mold top contact pads are below the top plane of mold compound **120**, longer contact terminals on interposer substrate **112** are required in order to reach the contact pads. Less warpage tolerances for both bottom package and interposer substrate **112** are allowed to ensure

contact between the interposer substrate terminals and the contact pads below the bottom package mold top surface.

Different types of device packages (flip chip, FBGA, etc.) can be mounted on the interposer substrate top surface **116**. More than one package can be mounted on the interposer substrate. Antenna(s), antenna array(s)/matrix(es), baluns for wireless applications, and passive components such as capacitors, inductors, and resistors can be mounted on interposer substrate **112**.

A gap (standoff) between interposer substrate **112** and first substrate **102** the top surface of mold compound **120** is allowed but not preferred. Contaminants can be trapped in this gap. These contaminants could cause shorting between adjacent contact pads on the mold top or between adjacent conductor posts **118**.

An air gap between interposer substrate bottom surface **114** and the top surface of mold compound **120** can be filled with adhesive material preformed on bottom surface **114** of interposer substrate **112**. For example, a layer of heat activated adhesive can be formed (coated or laminated) on bottom surface **114** of the interposer substrate **112**. During the manufacturing process of the interposer substrate-to-bottom package attachment, the adhesive layer is bonded to the bottom package mold top and fills the gap between interposer substrate **112** and the top surface of mold compound **120**. Examples of a suitable adhesive film can be the Tomoeagawa X adhesive or the Toray 8300 adhesive.

Interposer substrate **112** can be either stiff or flexible and can have either single conductor layer or multiple conductor layers. The conductor pillars **118** on the bottom surface **114** of the interposer substrate can be made of copper. Conductive posts **118** are exposed. A method of making copper pillars on a substrate is shown in published international application WO2006/028090, published Mar. 16, 2006, and titled "Member for Interconnecting Wiring Films and Method for Producing the Same."

FIGS. 2A-2D illustrate views of various embodiments of elements used to couple interposer substrate **112** to first substrate **102**. To enhance surface wetting during interposer substrate attachment to the bottom package contact pads, the tip of conductor posts **118** (see FIG. 2A) on bottom surface **114** can be plated with a layer **202** of solder, tin, tin and silver alloy, or other metal of non-metal materials (see FIG. 2B). Layer **202** can help to reduce oxidation and promote fusion between the conductor posts **118** on interposer substrate **112** and the contact pads on the bottom package mold top. A solder cap **204** (see FIG. 2(c)) can also be formed on the tip of conductor posts **118**, to promote fusion of the conductor posts **118** and the contact pads on bottom package mold top surface.

Small solder balls **206** (see FIG. 2D) or solder bumps can be attached directly on the bottom of the interposer substrate **112** to replace the copper pillars **118**. An interposer substrate **112** with solder bumps/balls **206** attached on bottom surface **114** is called a bumped substrate herein. The solder balls **206** can be attached to the interposer substrate bottom surface **114** using the same process as solder ball attachment to a ball grid array (BGA) package.

In the first step, a transfer pin applies solder flux onto substrate contact pads. The solder balls are then picked and place on the substrate. Finally reflow for ball-to-substrate attachment.

Small solder balls **206** can be the same or a different material as solder balls **110**. For example, Pb-free solder balls (Tin/silver/copper, tin/silver, etc.) can be used for both solder ball **206** and solder balls **110**.

A flexible substrate, such as Upilex-S polyimide tape substrate or a stiff substrate such as BT core with weaved glass

fiber cloth substrate, can be used as the interposer substrate **112**. Both organic materials and inorganic materials such BT, FR4, ceramic, glass, silicon can be used. Examples include a laminated BT substrate, an Ajinomoto Film (ABF) build-up flip chip (FC) substrate, and a through silicon via interposer.

An advantage of using solder balls **206** for the interconnect terminals of interposer substrate **112** is that the conventional solder ball or solder bump attachment method can be used in the ball-to-substrate attachment manufacturing process. On the other hand manufacturing throughput of a bumped interposer substrate can be substantially higher than when conductor posts **118** are used due to a reduced number of processing steps. For example, photo imaging, photo masking and plating or chemical etching processes required for making a conductor posts **118** are not needed in a bumped substrate manufacturing processes. Moreover, the processing cost of attaching solder balls **206** to interposer substrate **112** is much lower than for attaching conductor posts **118**.

Another important advantage of solder bumped substrate technology is that the height of the interconnect terminals can be two times higher or more than that of conductor posts **118**. For example, a typical height of conductor posts **118** is approximately 25-45 μm in today's conductor post substrate technology shown by WO 2006/028090, published Mar. 16, 2006, entitled "Member for Interconnecting Wiring Films and Method for Producing the Same," to Lijima et al., which is incorporated herein by reference in its entirety as though set forth in full below. In a solder ball attached interposer substrate, a solder ball height of 100 μm or more can be made using a conventional low cost manufacturing process.

An advantage of the package construction illustrated in FIG. 1 is that the vertical interconnection length between the bottom substrate **102** and components **122** is substantially shorter than the interconnection through a PCB. Since the interposer **112** has the shortest distance to the bottom substrate **102**, the interposer substrate **112** provides a low-impedance signal transmission path to the bottom package. This interconnection path enables high speed communication between an IC die located in the bottom package (not shown in FIG. 1) and components **122** mounted on interposer substrate **112**. The package construction in FIG. 1 provides a bottom substrate-to-top substrate high speed communication bus through the molded solder balls. Consequently, high speed communication between the bottom package and components **122** can be achieved.

As shown in FIG. 1, more than one component **122** can be mounted on interposer substrate **112**. Different types of packages (flip chip, FBGA, etc.) can be mounted on the interposer substrate.

FIGS. 3A and 3B illustrate views of variations in the manner in which conductor posts **118** can be attached to solder balls **110**. In FIG. 3A, a mold compound **320a** is truncated so that tops **308** of solder balls **110a** are flush with the top surface of mold compound **320a**. The mold compound **320a** can be sufficiently truncated such that the tops of solder balls **110a** are also removed to thereby form a circular solder pad flush with the top surface of mold compound **320a**. In a second embodiment shown in FIG. 3B, the top surface of mold compound **320b** is above the tops of solder balls **110**. The top surface of mold compound **320b** is drilled or etched in the regions above solder balls **110** to form openings **302** so that conductor posts **118** of interposer substrate **112** will be received in openings **302** and make contact with solder balls **110**.

The interposer substrate shown in FIGS. 1-3 has the same size as the bottom package. An interposer substrate with a size smaller than the bottom package can also be used. Addition-

ally, more than one interposer substrate can be attached to the bottom package using the same method and steps discussed above.

FIG. 4A illustrates a view of a molded SiP (system in package) packaging construction. Both top **114** and bottom **116** surfaces (not numerically referenced in FIG. 4A) of interposer substrate **112** have direct electrical interconnection with first substrate **102** of the bottom package. On bottom surface **114** of interposer substrate **112**, conductor posts **118** connect with first substrate **102** through the solder balls **110** in the bottom substrate package **102** at the contact pads on bottom substrate package top **106**. On the top surface **116** of the interposer substrate, a wire bond **402** connects interposer substrate **112** with first substrate **102** along the exposed periphery of bottom package substrate **102**. A second mold compound **406a** provides protection for the wire bond **402**.

The following manufacturing steps can be used to make a SiP package shown in FIG. 4A. The interposer substrate is attached to bottom package first mold compound. The component(s) is mounted to the interposer substrate top. A wire bond connection between the interposer substrate and bottom package SiP. Finally, encapsulate the bond wires and component(s) on the interposer substrate with a second mold compound.

Alternatively, the sequence of the above assembly processes of attaching the interposer substrate to bottom package first mold compound and mounting the component(s) to the interposer substrate top can be exchanged by mounting components on the interposer substrate before the interposer substrate is attached to the bottom package mold top.

In a second mold process, bottom surface **116** of interposer substrate **112** can be partially exposed in the center (see FIG. 4B). Components **122** can be mounted to the interposer substrate top after second mold compound **406b** is used to encapsulate the wire bonds **402**.

The following manufacturing steps can be used to make a SiP package shown in FIG. 4B. Attach an interposer substrate to a bottom package first mold compound. Then make a wire bond connection between the interposer substrate and bottom package substrate. Encapsulate the wire bonds and component(s) on the interposer substrate with a second mold compound. Finally mount the component(s) to the interposer substrate top.

Interposer substrate **412c** can have substantially the same size as first substrate **102** (see FIG. 4C). In this configuration, interposer substrate **112** top surface **416c** is not wire bonded to the bottom package.

FIG. 5A shows a closed 3-dimensional electrical potential surface formed by connecting the ground or power planes in both first substrate **102** and interposer substrate **112**. The interconnection of the substrate planes separated by mold compound **120** is accomplished with an array of solder balls **510**. Solder balls **510** can be substantially similar to solder balls **110**. The IC die (or dies) of the bottom package **102** is enclosed within a 3-dimensional electrical potential enclosure **504a** comprising substrates **102** and **112** and grounded solder balls **510**. This structure provides EMI emission protection by shielding electromagnetic radiation from as well as towards an IC die **506** inside the bottom package. For RF signal interconnection between the top and bottom packages, RF signal traces on the substrates at the top (interposer substrate **112**) and the bottom (first **102**) can be routed within the electrical potential enclosure to confine EMI emission within the enclosure. The 3-dimensional electrical potential enclosure is preferably maintained at ground or power potential. In other words, ground or power planes in the top and bottom substrates are preferred for the construction of the EMI shield

11

enclosure. In addition, connecting the bottom package ground or power plane with solder balls **510** and the planes of interposer substrate **112** can improve heat spreading from the bottom package IC die and improve the thermal performance of the SiP 3D packaging structure. In addition to FIG. 5A, the 3D SiP interconnection design can be partitioned in various manners to separate digital from analog as well as various RF signals. For example, FIG. 5B shows that inner row(s) of molded small solder balls **510b** can be used to construct the 3-dimensional electrical ground potential enclosure within the SiP. Multiple electrical potential enclosures **504b** and **504c** can be constructed as shown in FIG. 5C.

FIG. 24 shows a further embodiment of an IC structure having multiple interposer substrates. More particularly, FIG. 24 shows at least two interposer substrates **2420a** and **2420b**. Each interposer substrate has a first or bottom surface **2440a** and **2440b**, respectively, and a second or top surface **2460a** and **2460b**, respectively. Similar to the single interposer substrate embodiments, each interposer substrate **2420a** and **2420b** has contact posts or pillars **2480a** and **2480b**, respectively, which make physical and electrical contact with solder balls or bumps **110** on bottom substrate **102**. Various types of circuit components may be mounted on the multiple interposer substrates using wire bonding techniques (as shown for circuit component **2422a**) or solder post bonding techniques (as shown for circuit component **2422b**), or any other suitable mounting and connection technique. It will be apparent to anyone skilled in the relevant art that any number of interposer substrates may be mounted on the first substrate member. Further any number and type of circuit components (e.g., leadframe and BGA packages) may be mounted to each interposer substrate, depending on the needs of the circuit designers.

FIG. 6 shows a flowchart **600** providing example steps for assembling an IC package. Other structural and operational embodiments will be apparent to persons skilled in the relevant art(s) based on the following discussion. The steps shown in FIG. 6 do not necessarily have to occur in the order shown. The steps of FIG. 6 are described in detail below.

In step **602**, an IC die is mounted to a first surface of a substrate. For example, in FIG. 7, an IC die **702** is coupled to a first surface **704** of a substrate **706** using solder bumps **708**.

In step **604**, a first plurality of conductive elements is formed on the first surface of the substrate. For example, in FIG. 8, solder balls **802** are formed on first surface **704** of substrate **706**.

In step **606**, at least the IC die and the first surface of the substrate are encapsulated with an mold compound. For example, in FIG. 9, solder balls **802**, IC die **702**, and first surface **704** of substrate **706** are encapsulated in a mold compound **902**. As shown in FIG. 9, solder balls **802** are completely encapsulated in mold compound **902**. In another embodiment, however, portions of solder balls **802** may be exposed. For example, in the embodiment of FIG. 10, the tops of solder balls **802** are left exposed by mold compound **902**.

As described above, the steps of flowchart **600** do not have to be completed in the order shown in FIG. 6. For example, in one embodiment, step **606** can be completed before step **604**. For example, in FIG. 11, first surface **704** and IC die **702** can be encapsulated in a mold compound **1102**. As shown in FIG. 11, via holes **1104** can be formed in mold compound **1102**. In one embodiment, via holes **1104** can be formed in mold compound **1102** through a molding process where the mold chase is designed to have posts at the via holes locations preventing the molding compound from covering the certain regions (e.g., contact pads) on surface **704** of substrate **706**. Alternatively, via holes **1104** can be formed after mold encapsulation

12

by drilling through mold compound **1102** using a process such as laser drill or chemical etching. A first plurality of contact members can then be formed by filling the via holes with conductive material. For example, in FIG. 12, solder paste **1202** fills via holes **1104** (not numerically referenced in FIG. 12) to create a first plurality of conductive elements.

In step **607**, a portion of each of the first plurality of conductive elements is exposed. For example, in FIG. 13, the tops of solder balls **802** are exposed and truncated by removing a layer of mold compound **902**. As shown in FIG. 13, truncated solder balls **802** form contact pads on the same plane of the remaining mold compound top surface.

In another embodiment, portions of solder balls **802** can be exposed by drilling through the mold compound. For example, in FIG. 15, holes **1502** are drilled into mold compound **902** to expose top portions of solder balls **802**. Methods to drill through mold include such as mechanical drilling and chemical etching. Other drilling methods including laser ablation of the mold compound known in this field of art can also be used.

In an embodiment, step **607** can be optional. For example, in embodiments in which the encapsulation in step **606** is executed such that portions of the first plurality of conductive elements remain exposed, step **607** can be omitted. In another embodiment, a portion of the mold compound can be removed even when portions of the first plurality of conductive elements are exposed. For example, in the embodiment of FIG. 14, the tops of solder paste **1202** can be truncated by removing a layer of mold compound **1102**. In doing so, a level surface is created on the top surface of mold compound. In alternate embodiments, a flat surface can be created by flattening the tops surfaces of the first plurality of conductive elements through, e.g., ball, post, or bump coning processes.

In step **608**, a second plurality of conductive elements are formed on a second surface of an interposer substrate. In an embodiment, the second plurality of conductive elements can be a plurality of conductive posts. For example, in FIG. 16, conductive posts **1602** are formed on a surface **1604** of interposer substrate **1606**. In another embodiment, the plurality of conductive elements can be a plurality of contact pads. For example, in FIG. 17, contact pads **1702** are formed on surface **1604** of interposer substrate **1606**. Contact pads **1702** are substantially flush with surface **1604** of interposer substrate **1606**.

In step **610**, the first plurality of conductive elements are coupled to the second plurality of conductive elements. For example, in FIG. 18, conductive posts **1602** are coupled to solder balls **802**. In doing so, electrical interconnection between interposer substrate **1606** and substrate **706** is established. As shown in FIG. 18, interposer substrate **1606** is placed on a flat surface formed by mold compound **902** and solder balls **802**. In another embodiment, as described above, solder balls **802** can be exposed by drilling holes in the mold compound, thus, in the example of FIG. 19, conductive posts **1602** can be coupled to respective ones of solder balls **802** through the holes formed in mold compound **902**. In yet another embodiment, an adhesive can be used to facilitate the coupling process. For example, in FIG. 20, an adhesive layer **2002** (e.g., heat-activated adhesive) can be applied to surface **1604** to facilitate coupling between interposer substrate **1606** and the top surface of mold compound **902**.

Moreover, as described above, solder paste filled into via holes can be used instead of solder balls for the first plurality of conductive elements. Thus, in the example of FIG. 21, conductive posts **1602** can be coupled to solder paste **1202**, e.g., through a reflow process.

13

In another embodiment, as described above, contact pads can be used instead of conductive posts for the second plurality of conductive elements. Thus, in the example of FIG. 22, solder paste 1202 is coupled to contact pads 1702.

In step 612, at least one circuit member is mounted on a first surface of the interposer substrate. For example, passive components such as capacitors, inductors, electromagnetic coupling baluns, electromagnetic radiators, antennas, resistors, etc. can also be mounted on the first surface of the interposer substrate. For example, in FIG. 23, first and second circuit members 2302 and 2304 are coupled to surface 2306 of interposer substrate 1606.

Note that step 612 can be performed before step 610 where components or packages can be mounted onto the interposer substrate before the assembly is attached to the bottom package mold top. For example, passive components such as capacitors, inductors, electromagnetic coupling baluns, electromagnetic radiators, antennas, resistors, etc. can also be mounted on the top of interposer substrate 112.

CONCLUSION

While various embodiments of the present disclosure have been described above, it should be understood that they have been presented by way of example only, and not limitation. It will be apparent to persons skilled in the relevant art that various changes in form and detail can be made therein without departing from the spirit and scope of the disclosure. Thus, the breadth and scope of the present disclosure should not be limited by any of the above-described exemplary embodiments, but should be defined only in accordance with the following claims and their equivalents.

What is claimed is:

1. A method of manufacturing an integrated circuit (IC) package, comprising:

mounting a first plurality of contact members on a surface of a package member;

encapsulating the first plurality of contact members with a mold compound to form a molding layer;

forming a plurality of cavities in the mold compound to expose respective surfaces of a first plurality of conductive elements;

inserting a second plurality of contact members located on a first surface of an interposer substrate into the plurality of cavities such that the second plurality of contact members contact corresponding ones of the first plurality of contact members and such that a surface of the molding layer contacts the first surface of the interposer substrate, wherein the interposer substrate is configured such that a circuit member mounted to a second surface of the interposer substrate is electrically coupled to the first plurality of contact members.

2. The method of claim 1, further comprising: mounting an IC die to the surface of the package member, wherein the IC die is electrically coupled to the first plurality of contact members.

3. The method of claim 1, further comprising: removing a portion of the mold compound such that a surface of each of the first plurality of contact members is substantially flush with the surface of the molding layer.

4. The method of claim 1, further comprising: forming the second plurality of contact members on the first surface of the interposer substrate.

5. The method of claim 1, further comprising: mounting the circuit member to the second surface of the interposer substrate.

14

6. The method of claim 5, wherein the circuit member comprises a ball grid array (BGA) package, and wherein mounting the circuit member comprises:

mounting the BGA package to the second surface of the interposer substrate.

7. The method of claim 5, wherein the circuit member comprises a leadframe package, and wherein mounting the circuit member comprises:

mounting the leadframe package to the second surface of the interposer substrate.

8. The method of claim 1, wherein the second plurality of contact members comprise conductive posts extending from the first surface of the interposer substrate to make contact with respective ones of the first plurality of contact members.

9. The method of claim 1, wherein the inserting further comprises:

inserting the second plurality of contact members into the plurality of cavities such that a Faraday cage is formed when an outer periphery of the second plurality of contact members is coupled to corresponding ones of the first plurality of contact members.

10. The method of claim 1, wherein mounting comprises: mounting a plurality of solder balls on the surface of the package member.

11. The method of claim 1, wherein the second plurality of contact members comprises a plurality of solder balls, and wherein the method further comprises:

coupling the plurality of solder balls to corresponding ones of the first plurality of contact members.

12. The method of claim 1, wherein the interposer substrate comprises a plurality of conductor layers.

13. The method of claim 1, further comprising: forming the package member.

14. The method of claim 13, wherein forming comprises: forming a trace that is configured to shield radiation.

15. The method of claim 1, further comprising: encapsulating at least a portion of the surface of the package member and at least a portion of the second surface of the interposer substrate.

16. The method of claim 15, wherein the encapsulating at least the portion of the surface of the package member further comprises:

encapsulating all of the second surface of the interposer substrate.

17. The method of claim 1, further comprising: mounting the circuit member and a second circuit member to the second surface of the interposer substrate.

18. A method of manufacturing an integrated circuit (IC) package, comprising:

mounting a first plurality of contact members on a surface of a package member;

encapsulating the first plurality of contact members with a mold compound to form a molding layer;

forming a plurality of cavities in the mold compound to expose respective surfaces of a first plurality of conductive elements; and

inserting a second plurality of contact members located on a surface of an interposer substrate into the plurality of cavities such that the second plurality of contact members contact the first plurality of contact members and such that a surface of the molding layer is flush with the surface of the interposer substrate.

19. The method of claim 18, further comprising: removing a portion of the mold compound such that a surface of the first plurality of contact members is substantially flush with the surface of the molding layer.

15

20. The method of claim **18**, wherein the second plurality of contact members comprise conductive posts extending from the surface of the interposer substrate to make contact with the first plurality of contact members.

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5

16